
EASY SOUND[®]

eSE Series

**Tiny Controller-Based Speech
Synthesizer with PWM Output**

Product Specification

Doc. VERSION 1.1

ELAN MICROELECTRONICS CORP.


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Specification Revision History

Doc. Version	Revision Description	Date
1.0	Initial version	2004/01/13
1.1	Modify eSA020 ROM Size from 60Kx10 to 64Kx10	2005/01/11



1 General Description

eSE Series is a series of 3 to 80 seconds single chip high quality voice synthesizer IC that provides strong features and uses improved algorithm for achieving pure speech. It is based on a tiny controller and is very suitable for low cost high quality toy market application.

2 Features

- 3 to 80 seconds voice capacity
- 5-bit ASPCM+ speech synthesis
- Port 2 provides wake-up function
- Power down mode for energy saving
- One 6 bit timer overflow control is provided
- 38KHz modulation for IR transmission
- Two stacks for subroutine call
- Direct Drive PWM output for voice
- Sample rate (KHz) : 3.7 / 4.3 / 5 / 6 / 7.5 / 10 / 15

Product	eSE003	eSE005	eSE007	eSE009	eSE012	eSE015
Duration (@ 6K sample rate)	3 sec	5 sec	7 sec	9 sec	12 sec	15 sec
ROM (bits)	10Kx10	16Kx10	28Kx10	32Kx10	44Kx10	48Kx10
PROG. ROM (bits)	8Kx10	16Kx10				
RAM (bits)	32x4		48x4		64x4	
I/O pins	2 I/O	4 I/O			6 I/O	
	P2.0, P2.1	P2.0, P2.1, P3.2, P3.3			P2.0, P2.1, P2.2, P3.1, P3.2, P3.3	
IR	No	Yes				
Voice silence compression	No	Yes				
Flash with Volume (pin)	Yes (P2.1)	Yes (P3.3)				



Product	eSE020	eSE030	eSE040	eSE060	eSE080
Duration (@ 6K sample rate)	20 sec	30 sec	40 sec	60 sec	80 sec
ROM (bits)	64Kx10	96Kx10	128Kx10	192Kx10	256Kx10
PROG. ROM (bits)	32Kx10				
RAM (bits)	64x4				
I/O pins	8 I/O				
	P2.0, P2.1, P2.2, P2.3, P3.0, P3.1, P3.2, P3.3				
IR	Yes				
Voice silence compression	Yes				
Flash with Volume (pin)	Yes (P3.3)				

3 Pin Descriptions

Symbol	I/O	Function
P2.0	I/O	Bit 0 of Port 2
P2.1	I/O	Bit 1 of Port 2
P2.2	I/O	Bit 2 of Port 2 (excluding eSE003, eSE005, eSE007, & eSE009)
P2.3	I/O	Bit 3 of Port 2 (excluding eSE003, eSE005, eSE007, eSE009, eSE012, & eSE015)
P3.0	I/O	Bit 0 of Port 3 (excluding eSE003, eSE005, eSE007, eSE009, eSE012, & eSE015)
P3.1	I/O	Bit 1 of Port 3 (excluding eSE003, eSE005, eSE007, & eSE009)
P3.2	I/O	Bit 2 of Port 3 (excluding eSE003)
P3.3	I/O	Bit 3 of Port 3 (excluding eSE003)
VDD	I	Positive digital power supply.
OSCI	I	Ring oscillator input pin.
VSSD	I	Negative digital power supply.
VCC	I	Positive analog power supply
VSSC	I	Negative analog power supply
VO1	O	PWM output 1
VO2	O	PWM output 2



4 Absolute Maximum Ratings

Items	Symbol	Min	Max	Unit
Supply Voltage	VDD-VSS	-0.3	+6.0	V
Input Voltage	VIN	VSS -0.3	VDD+0.3	V
Operating Temperature	TOP	-20.0	+70.0	0C
Storage Temperature	TSTG	-55.0	+125.0	0C

5 Electrical Characteristics

(25°C, Vdd=3.0 Volts unless otherwise specified)

Items	Sym	Min.	Typ.	Max.	Unit	Condition
Operating Voltage	VDD	2.2	3.0	5.5	V	-
Standby Current	IDDS	-	-	2.0	uA	VDD=3V
Operating Current	IDDO	-	250	350	uA	VDD=3V, no load, PWM D/A stop
P2, P3 Drive Current	IOD	2.0	3.0	4.5	mA	VDD=3V, VO=2.4V
P2 Sink Current	IOS	-	3.0	10.0	uA	VDD=3V
P3 Sink Current	IOS	2.3	3.5	4.5	mA	VDD=3V, VO=0.4V
VO1, VO2 Output Current	IVO	150	180	-	mA	VDD=3V, Vo1=Vo2=1.5 V
Oscillation Resistor	R	-	220	-	KΩ	VDD=3V
Oscillation Freq.	FOSC	1.75	1.92	2.1	MHz	VDD=3V

6 Application Circuit

Important notes for the following application circuits:

- For noisy power supply application, suppress noise by adding a 0.1μF ceramic capacitor between-
 - Ground and power VCC & IC's VCC pad
 - Ground and power VCC & IC's VDD pad
- For heavy loading application, it is recommended that an electrolytic capacitor is added between VCC and ground. The recommended capacitor value for button cell applications is 10μF.
- The recommended value for button cell internal impedance is 750Ω or less.
- The use of spring direct trigger is not recommended. If you must use such trigger, you need to add a ceramic capacitor between trigger pin and ground to debounce the spring noise. The recommend capacitor value is 0.001 ~ 0.01 μF.

6.1 Heavy Noise Application Circuit

